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An Unprecedented Pentanary Chalcogenide with the Mn Atoms in Two Chemical Environments: Unique Bonding Characteristics and Magnetic Properties

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Experimental Section

Materials and Instruments

Energy dispersive X-ray (EDX, Oxford INCA) spectra were performed on a field emission scanning electron microscope (FESEM, JSM6700F) equipped with an X-ray spectroscope. Powder X-ray diffraction (PXRD) patterns of polycrystalline material were collected on a Rigaku Mini-Flex II powder diffractometer by using Cu- K_{α} radiation ($\lambda = 1.5416 \text{ \AA}$) in the range of $10\text{--}60^{\circ}$ (2θ) with a step size of 0.02° . The PXRD data were analyzed using a profile fitting by a least-squares method employing the computer program GSAS implemented with EXPGUI.¹ The UV-Vis-NIR diffuse reflectance spectra were measured on a Perkin-Elmer Lambda 950 UV-Vis spectrophotometer at room temperature in the wavelength range of 190–2500 nm and

Electronic Supplementary Information

BaSO₄ was used as a standard (100% reflectance). The absorption spectrum was calculated from the reflection spectra using the Kubelka–Munk function: $\alpha/S = (1-R)^2/2R$, where α was the absorption coefficient, S was the scattering coefficient, and R was the reflectance.² Magnetic measurements were performed using a commercial Quantum Design Physical Property Measurement System (PPMS). The ground single-crystal powder sample was placed in a gel capsule sample holder suspended in a plastic drinking straw. Magnetic susceptibility was measured at 1000 Oe from 300 to 2 K, and magnetization was measured at 2 K in an applied field from -8 to 8 T (field scan of 0.1 T per step). Moreover, low-temperature magnetic susceptibility was also measured with field cooling (FC) and zero-field-cooling (ZFC) regimes from 2 to 50 K under 50 Oe.

Synthesis of Cs₂[Mn₂Ga₃S₇Cl] (1). The title compound resulted unexpectedly, since the initial objective was to prepare single crystals of quaternary “CsMn₄Ga₅S₁₂”. Compound **1** was obtained from a mixture of 4.0 mmol Mn (5N, Alfa Aesar China (Tianjin) Co., Ltd.), 5.0 mmol Ga (5N, Sinopharm Chemical Reagent Co., Ltd.) and 12.0 mmol S (5N, Sinopharm Chemical Reagent Co., Ltd.) together with 5.0 mmol CsCl (4N, Sinopharm Chemical Reagent Co., Ltd.) in a fused-silica tube under 10⁻³ Pa atmosphere, and finally placed in a temperature-controlled tube furnace. The reactants were gradually heated to 1223 K and held there for 3 days, then slowly cooled to 623 K at a rate of 3 K/h before cutting off the furnace. The products were washed with distilled water and dried by an ethanol, after such a treatment, light-orange plates of **1** (70% yield) and red blocks of CsMn₃Ga₅S₁₁³ were obtained. Many

Electronic Supplementary Information

attempts to increase the yield were failed, including starting reaction, loading ratio, and annealing temperature. Therefore, handpicked crystals of **1** were used to measure all the properties reported herein. The purity of target product was confirmed by PXRD study, in which the experimental PXRD pattern is in good agreement with the simulated data based on the single-crystal XRD model. The crystals of **1** were stable in the air for several months.

Single crystal X-ray Crystallography. The single-crystal diffraction data collections was taken on a Mercury CCD equipped with graphite-monochromated Mo- K_{α} radiation ($\lambda = 0.71073 \text{ \AA}$) at room-temperature. The absorption correction was done⁴ and the structure was solved by the direct methods and refined by the full-matrix least-square fitting on F^2 using the *SHELX-2014* software.⁵ All of the non-hydrogen atoms were refined with anisotropic thermal parameters and the coordinates were standardized using *STRUCTURE TIDY*.⁶ It is difficult to distinguish S and Cl atoms by diffraction data because their X-ray scattering factors are similar, but the identity can be assigned according to the valence bond sum (VBS) method, $V_i = \sum S_{ij}$, where the bond valence (S_{ij}) is calculated by $S_{ij} = \exp[(R_{ij}-d_{ij})/0.37]$, d_{ij} is bond length between nearest neighboring atoms $i-j$, and R_{ij} is the tabulated parameter. Moreover, such VBS results about the S/Cl ratio were in good agreement with the EDX data and charge balance requirement.⁷ The refinement details are summarized in Table S1. The positional coordinates and isotropic equivalent thermal parameters are given in Table S2, and the selected bond distances are listed in Table S3.

Electronic Supplementary Information

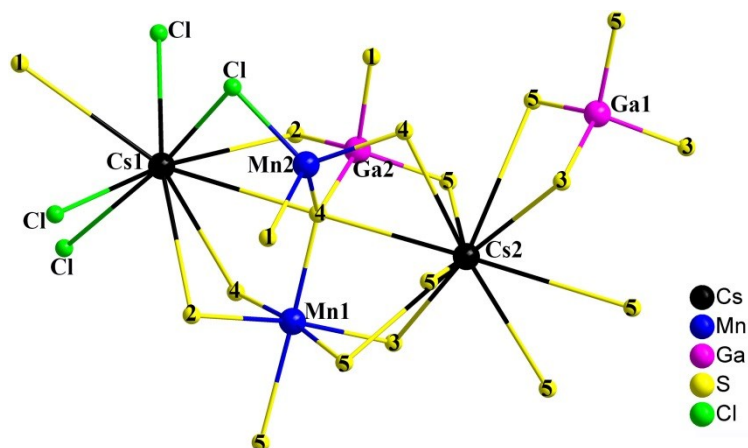


Figure S1. Coordination geometry of $\text{Cs}_2[\text{Mn}_2\text{Ga}_3\text{S}_7\text{Cl}]$.

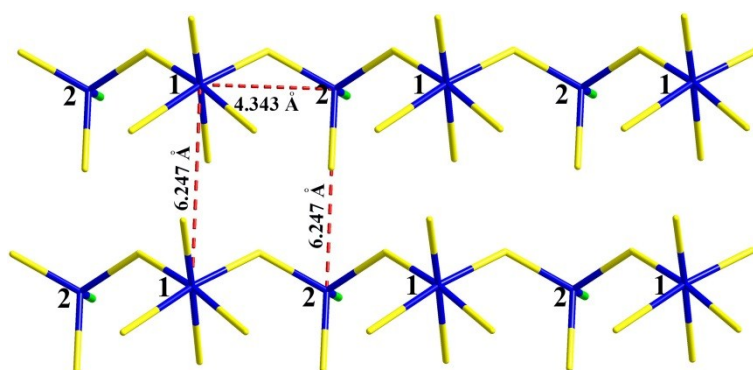


Figure S2. Schematic of 1D $[\text{Mn}_2\text{S}_7\text{Cl}]^{11-}$ chain, chains of $[\text{Mn}_1\text{S}_6]$ and $[\text{Mn}_2\text{S}_3\text{Cl}]$ connected by sharing S atoms. Blue: Mn; yellow: S; green: Cl.

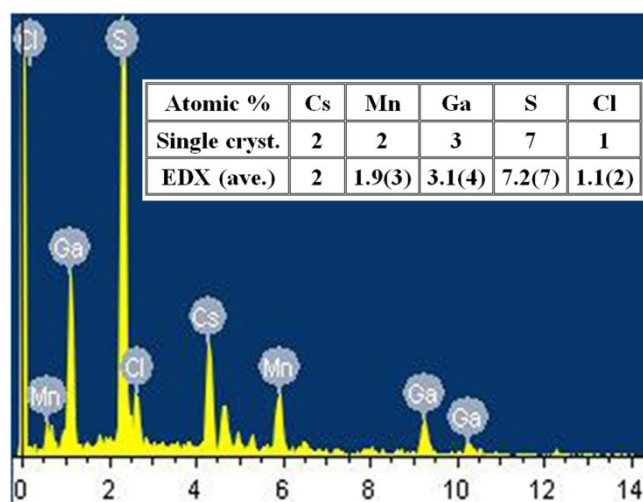


Figure S3. The EDX results of $\text{Cs}_2[\text{Mn}_2\text{Ga}_3\text{S}_7\text{Cl}]$.

Electronic Supplementary Information

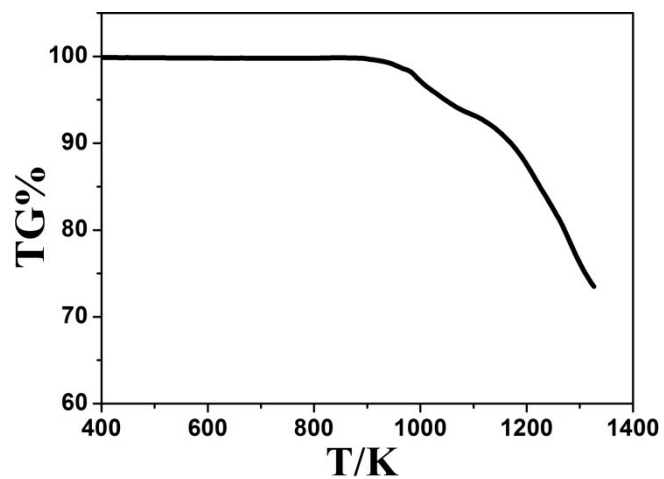


Figure S4. The TG curve of Cs₂[Mn₂Ga₃S₇Cl].

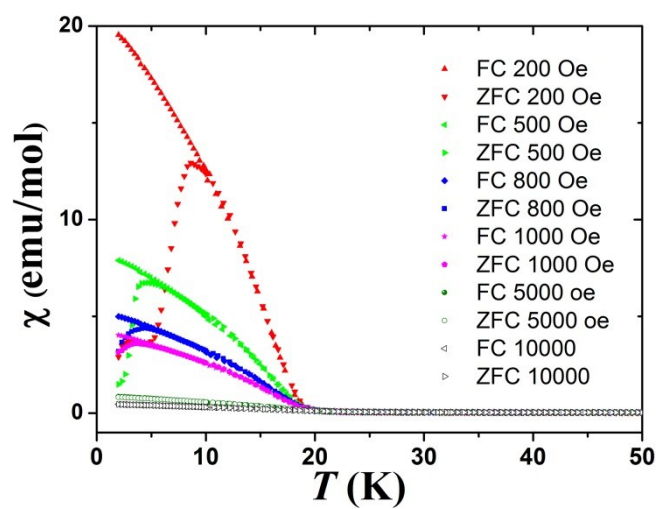


Figure S5. FC and ZFC curves at different fields.

Electronic Supplementary Information

Table S1. Crystallographic data and refinement details for Cs₂[Mn₂Ga₃S₇Cl].

Empirical formula	Cs ₂ [Mn ₂ Ga ₃ S ₇ Cl]
Formula weight	844.73
Temperature(K)	293(2)
Crystal system	Orthorhombic
Space group	<i>Pnma</i> (No.62)
<i>a</i> (Å)	6.2467(6)
<i>b</i> (Å)	7.3879(8)
<i>c</i> (Å)	33.600(3)
<i>V</i> (Å ³)	1550.6(3)
<i>Z</i>	4
<i>D_c</i> (g·cm ⁻³)	3.62
μ (mm ⁻¹)	12.43
GOOF on <i>F</i> ²	1.092
<i>R</i> ₁ , <i>wR</i> ₂ (<i>I</i> > 2σ(<i>I</i>)) ^a	0.0381, 0.0944
<i>R</i> ₁ , <i>wR</i> ₂ (all data)	0.0492, 0.1000
Largest diff. peak and hole (e·Å ⁻³)	1.592, -1.415

^a: $R_1 = \sum ||F_o| - |F_c|| / \sum |F_o|$, $wR_2 = [\sum w(F_o^2 - F_c^2)^2 / \sum w(F_o^2)^2]^{1/2}$

Electronic Supplementary Information

Table S2. Atomic coordinates and equivalent isotropic displacement parameters of Cs₂[Mn₂Ga₃S₇Cl].

Atom	Wyckff	<i>x</i>	<i>y</i>	<i>z</i>	$U_{\text{eq}}(\text{\AA})^a$
Cs1	4 <i>c</i>	0.2727(2)	0.25	0.02641(2)	0.0292(2)
Cs2	4 <i>c</i>	0.2320(2)	0.25	0.71113(2)	0.0290(3)
Mn1	4 <i>c</i>	0.0630(3)	0.25	0.15392(5)	0.0149(4)
Mn2	4 <i>c</i>	0.3530(3)	0.25	0.58777(5)	0.0132(4)
Ga1	4 <i>c</i>	0.1450(2)	0.25	0.28237(3)	0.0107(3)
Ga2	8 <i>d</i>	0.1378(2)	0.0039(0)	0.37622(2)	0.0116(2)
S1	4 <i>c</i>	0.2463(4)	0.25	0.91021(7)	0.0114(6)
S2	4 <i>c</i>	0.2894(4)	0.25	0.40663(7)	0.0125(6)
S3	4 <i>c</i>	0.2799(5)	0.25	0.21961(7)	0.0151(6)
S4	8 <i>d</i>	0.2798(3)	0.0064(2)	0.12214(6)	0.0165(5)
S5	8 <i>d</i>	0.2818(3)	0.0013(2)	0.31330(5)	0.0136(4)
Cl	4 <i>c</i>	0.2731(5)	0.25	0.51931(9)	0.0340(8)

U_{eq} is defined as one third of the trace of the orthogonalized U_{ij} tensor.

Electronic Supplementary Information

Table S3. Selected bond lengths (Å) of Cs₂[Mn₂Ga₃S₇Cl].

Mn1–S4 ×2	2.493(2)	Cs1–S4 ×2	3.686(2)
Mn1–S3	2.590(3)	Cs1–S2	3.765(3)
Mn1–S2	2.657(3)	Cs1–S1	3.908(3)
Mn1–S5 ×2	2.771(2)	Cs1–S2	3.935(3)
Mn2–S4 ×2	2.368(2)	Cs1–Cl	3.478(3)
Mn2–S1	2.458(3)	Cs1–Cl	3.483(3)
Mn2–Cl	2.354(3)	Cs1–Cl ×2	3.7126(5)
Ga1–S3	2.271(3)	Cs2–S4 ×2	3.540(2)
Ga1–S5 ×2	2.278(2)	Cs2–S5 ×2	3.653(2)
Ga1–S3	2.281(3)	Cs2–S3 ×2	3.7057(5)
Ga2–S4	2.237(2)	Cs2–S5 ×2	3.797(2)
Ga2–S2	2.291(2)	Cs2–S5 ×2	3.904(2)
Ga2–S5	2.297(2)		
Ga2–S1	2.312(2)		

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